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ISSUE CLASSIFICATION	
Class	Subclass

PATENT NUMBER

O.I.P.E. SCANNED <u>HKM3</u> Q.A.	O.G. PUBLICATION DATE	REISSUE PATENT DATE
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APPLICATION NO. 09/986997	CONT/PRIOR D F	CLASS 438	SUBCLASS 46	ART UNIT 2823	EXAMINER L. P. K.
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APPLICANTS

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TITLE

Method for fabricating semiconductor device having group III nitride

PTO-2040
12/89

☐ SURRENDER OF ORIGINAL PATENT _____ (Exr. Initials) ORIGINAL PATENT NUMBER _____

[illegible]

<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS		CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.	_____ (Assistant Examiner) _____ (Date)		NOTICE OF ALLOWANCE MAILED	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S Patent. No. _____	_____ (Primary Examiner) _____ (Date)		ISSUE FEE	
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FINAL SPRE REVIEW _____ (INITIALS)	_____ (Legal Instruments Examiner) _____ (Date)		ISSUE BATCH NUMBER	

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